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** CONTINUING DATA ***** ☒
 This application is a DIV of 09/596,116 06/16/2000 PAT 6,436,526

** FOREIGN APPLICATIONS ***** ☒
 JAPAN 11-170486 06/17/1999
 JAPAN 11-352962 12/13/1999

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35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> Met after Allowance				
Verified and Acknowledged	Examiner's Signature	Initials		

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TITLE

Magneto-resistance effect element magneto-resistance effect memory cell, MRAM, and method for performing information write to or read from the magneto-resistance effect memory cell

<input type="checkbox"/> All Fees
<input type="checkbox"/> 1.16 Fees (Filing)